

## LM7171QML Very High Speed, High Output Current, Voltage Feedback Amplifier

Check for Samples: [LM7171QML](#), [LM7171QML-SP](#)

### FEATURES

- (Typical Unless Otherwise Noted)
- Easy-To-Use Voltage Feedback Topology
- Very High Slew Rate: 2400V/ $\mu$ s
- Wide Unity-Gain Bandwidth: 200 MHz
- -3 dB Frequency @  $A_V = +2$ : 220 MHz
- Low Supply Current: 6.5 mA
- High Open Loop Gain: 85 dB
- High Output Current: 100 mA
- Specified for  $\pm 15V$  and  $\pm 5V$  Operation
- Available with Radiation Guarantee
  - Total Ionizing Dose 300 Krad(Si)
  - ELDRS Free 300 Krad(Si)

### APPLICATIONS

- HDSL and ADSL Drivers
- Multimedia Broadcast Systems
- Professional Video Cameras
- Video Amplifiers
- Copiers/Scanners/Fax
- HDTV Amplifiers
- Pulse Amplifiers and Peak Detectors
- CATV/Fiber Optics Signal Processing

### Connection Diagram

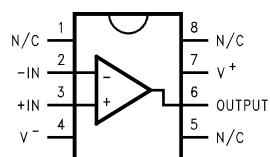


Figure 1. 8-Pin CDIP Top View

### DESCRIPTION

The LM7171 is a high speed voltage feedback amplifier that has the slewing characteristic of a current feedback amplifier; yet it can be used in all traditional voltage feedback amplifier configurations. The LM7171 is stable for gains as low as +2 or -1. It provides a very high slew rate at 4100V/ $\mu$ s and a wide unity-gain bandwidth of 200 MHz while consuming only 6.5 mA of supply current. It is ideal for video and high speed signal processing applications such as HDSL and pulse amplifiers. With 100 mA output current, the LM7171 can be used for video distribution, as a transformer driver or as a laser diode driver.

Operation on  $\pm 15V$  power supplies allows for large signal swings and provides greater dynamic range and signal-to-noise ratio. The LM7171 offers low SFDR and THD, ideal for ADC/DAC systems. In addition, the LM7171 is specified for  $\pm 5V$  operation for portable applications.

The LM7171 is built on Texas Instruments's advanced VIP™ III (Vertically integrated PNP) complementary bipolar process.

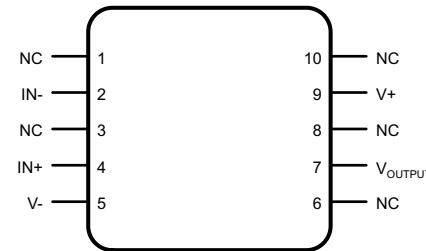


Figure 2. 10-Pin CFP Top View

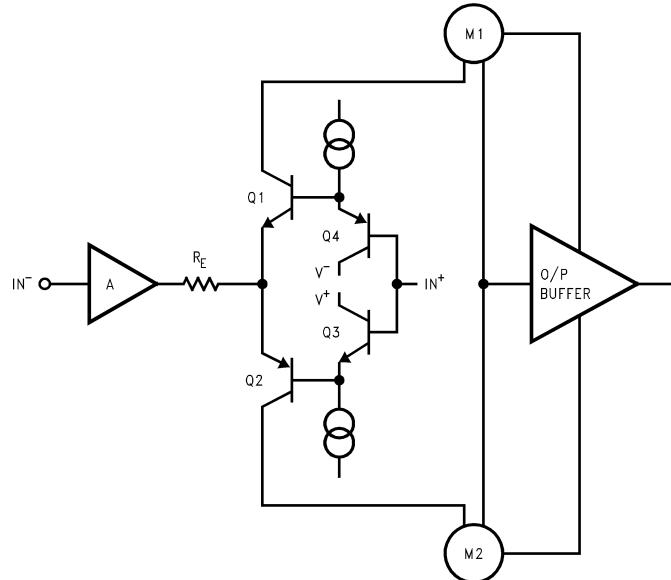


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## Simplified Schematic Diagram

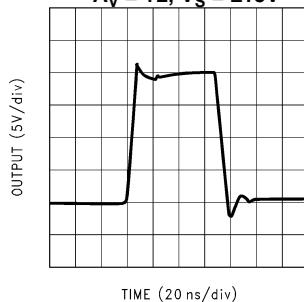


**Note:** M1 and M2 are current mirrors.

## Typical Performance

## Large Signal Pulse Response

$$A_V = +2, V_S = \pm 15V$$



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

**Absolute Maximum Ratings<sup>(1)</sup>**

Supply Voltage ( $V^+ - V^-$ )			36V
Differential Input Voltage <sup>(2)</sup>			$\pm 10V$
Maximum Power Dissipation <sup>(3)</sup>			730mW
Output Short Circuit to Ground <sup>(4)</sup>			Continuous
Storage Temperature Range			$-65^{\circ}C \leq T_A \leq +150^{\circ}C$
Thermal Resistance <sup>(5)</sup>	$\theta_{JA}$	8LD CDIP (Still Air)	106°C/W
		8LD CDIP (500LF/Min Air flow)	53°C/W
		10LD CFP (Still Air)	182°C/W
		10LD CFP (500LF/Min Air flow)	105°C/W
		10LD CFP "WG" (device 01, 02) (Still Air)	182°C/W
		10LD CFP "WG" (device 01, 02) (500LF/Min Air flow)	105°C/W
	$\theta_{JC}$	8LD CDIP	3°C/W
Package Weight (Typical)		10LD CFP	5°C/W
		10LD CFP "WG" (device 01, 02) <sup>(6)</sup>	5°C/W
Maximum Junction Temperature <sup>(3)</sup>			150°C
ESD Tolerance <sup>(7)</sup>			3000V

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For specified specifications and test conditions, see the Electrical Characteristics. The specified specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (2) Differential input voltage is applied at  $V_S = \pm 15V$ .
- (3) The maximum power dissipation must be derated at elevated temperatures and is dictated by  $T_{Jmax}$  (maximum junction temperature),  $\theta_{JA}$  (package junction to ambient thermal resistance), and  $T_A$  (ambient temperature). The maximum allowable power dissipation at any temperature is  $P_{Dmax} = (T_{Jmax} - T_A)/\theta_{JA}$  or the number given in the Absolute Maximum Ratings, whichever is lower.
- (4) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C.
- (5) All numbers apply for packages soldered directly into a PC board.
- (6) The package material for these devices allows much improved heat transfer over our standard ceramic packages. In order to take full advantage of this improved heat transfer, heat sinking must be provided between the package base (directly beneath the die), and either metal traces on, or thermal vias through, the printed circuit board. Without this additional heat sinking, device power dissipation must be calculated using  $\theta_{JA}$ , rather than  $\theta_{JC}$ , thermal resistance. It must not be assumed that the device leads will provide substantial heat transfer out the package, since the thermal resistance of the leadframe material is very poor, relative to the material of the package base. The stated  $\theta_{JC}$  thermal resistance is for the package material only, and does not account for the additional thermal resistance between the package base and the printed circuit board. The user must determine the value of the additional thermal resistance and must combine this with the stated value for the package, to calculate the total allowed power dissipation for the device.
- (7) Human body model, 1.5 k $\Omega$  in series with 100 pF.

**Recommended Operating Conditions<sup>(1)</sup>**

Supply Voltage	5.5V $\leq V_S \leq 36V$
Operating Temperature Range	$-55^{\circ}C \leq T_A \leq +125^{\circ}C$

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For specified specifications and test conditions, see the Electrical Characteristics. The specified specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

**Table 1. Quality Conformance Inspection Mil-Std-883, Method 5005 - Group A**

Subgroup	Description	Temp °C
1	Static tests at	25
2	Static tests at	125
3	Static tests at	-55
4	Dynamic tests at	25
5	Dynamic tests at	125
6	Dynamic tests at	-55
7	Functional tests at	25
8A	Functional tests at	125
8B	Functional tests at	-55
9	Switching tests at	25
10	Switching tests at	125
11	Switching tests at	-55
12	Settling time at	25
13	Settling time at	125
14	Settling time at	-55

**LM7171 ( $\pm 15$ ) Electrical Characteristics DC Parameters<sup>(1)(2)</sup>**

The following conditions apply, unless otherwise specified.

DC:  $T_J = 25^\circ\text{C}$ ,  $V^+ = +15\text{V}$ ,  $V^- = -15\text{V}$ ,  $V_{CM} = 0\text{V}$ , and  $R_L > 1\text{M}\Omega$

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
$V_{IO}$	Input Offset Voltage			-1.0	1.0	mV	1
				-7.0	7.0	mV	2, 3
$+I_{IB}$	Input Bias Current				10	$\mu\text{A}$	1
					12	$\mu\text{A}$	2, 3
$-I_{IB}$	Input Bias Current				10	$\mu\text{A}$	1
					12	$\mu\text{A}$	2, 3
$I_{IO}$	Input Offset Current			-4.0	4.0	$\mu\text{A}$	1
				-6.0	6.0	$\mu\text{A}$	2, 3
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 10\text{V}$		85		dB	1
				70		dB	2, 3
PSRR	Power Supply Rejection Ratio	$V_S = \pm 15\text{V}$ to $\pm 5\text{V}$		85		dB	1
				80		dB	2, 3
$A_V$	Large Signal Voltage Gain	$R_L = 1\text{K}\Omega$ , $V_O = \pm 5\text{V}$	See <sup>(3)</sup>	80		dB	1
			See <sup>(3)</sup>	75		dB	2, 3
		$R_L = 100\Omega$ , $V_O = \pm 5\text{V}$	See <sup>(3)</sup>	75		dB	1
			See <sup>(3)</sup>	70		dB	2, 3
$V_O$	Output Swing	$R_L = 1\text{K}\Omega$		13	-13	V	1
				12.7	-12.7	V	2, 3
		$R_L = 100\Omega$		10.5	-9.5	V	1
				9.5	-9.0	V	2, 3
	Output Current (Open Loop)	Sourcing $R_L = 100\Omega$	See <sup>(4)</sup>	105		mA	1
			See <sup>(4)</sup>	95		mA	2, 3
		Sinking $R_L = 100\Omega$	See <sup>(4)</sup>		-95	mA	1
			See <sup>(4)</sup>		-90	mA	2, 3
$I_S$	Supply Current				8.5	mA	1
					9.5	mA	2, 3

- (1) Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics except as listed in the Post Radiation Limits Table. These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate effect. Radiation end point limits for the noted parameters are specified only for the conditions as specified in MIL-STD-883, per Test Method 1019, Condition A.
- (2) Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics except as listed in the Post Radiation Limits Table. Low dose rate testing has been performed on a wafer-by-wafer basis, per Test Method 1019, Condition D of MIL-STD-883, with no enhanced low dose rate sensitivity (ELDRS).
- (3) Large signal voltage gain is the total output swing divided by the input signal required to produce that swing. For  $V_S = \pm 15\text{V}$ ,  $V_{OUT} = \pm 5\text{V}$ . For  $V_S = \pm 5\text{V}$ ,  $V_{OUT} = \pm 1\text{V}$ .
- (4) The open loop output current is specified, by the measurement of the open loop output voltage swing, using  $100\Omega$  output load.

**LM7171 ( $\pm 15$ ) Electrical Characteristics AC Parameters<sup>(1)(2)</sup>**

The following conditions apply, unless otherwise specified.

AC:  $T_J = 25^\circ\text{C}$ ,  $V^+ = +15\text{V}$ ,  $V^- = -15\text{V}$ ,  $V_{CM} = 0\text{V}$ , and  $R_L > 1\text{M}\Omega$

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
SR	Slew Rate	$A_V = 2$ , $V_I = \pm 2.5\text{V}$ 3nS Rise & Fall time	See <sup>(3)(4)</sup>	2000		V/ $\mu\text{S}$	4
GBW	Unity-Gain Bandwidth		See <sup>(5)</sup>	170		MHz	4

- (1) Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics except as listed in the Post Radiation Limits Table. These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate effect. Radiation end point limits for the noted parameters are specified only for the conditions as specified in MIL-STD-883, per Test Method 1019, Condition A.
- (2) Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics except as listed in the Post Radiation Limits Table. Low dose rate testing has been performed on a wafer-by-wafer basis, per Test Method 1019, Condition D of MIL-STD-883, with no enhanced low dose rate sensitivity (ELDRS).
- (3) See AN00001 for SR test circuit.
- (4) Slew Rate measured between  $\pm 4\text{V}$ .
- (5) See AN00002 for GBW test circuit.

**LM7171 ( $\pm 15$ ) Electrical Characteristics DC Drift Parameters<sup>(1)(2)</sup>**

The following conditions apply, unless otherwise specified.

DC:  $T_J = 25^\circ\text{C}$ ,  $V^+ = +15\text{V}$ ,  $V^- = -15\text{V}$ ,  $V_{CM} = 0\text{V}$ , and  $R_L > 1\text{M}\Omega$

Delta calculations performed on QMLV devices at group B, subgroup 5.

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
$V_{IO}$	Input Offset Voltage			-250	250	$\mu\text{V}$	1
$+I_{Bias}$	Input Bias Current			-500	500	nA	1
$-I_{Bias}$	Input Bias Current			-500	500	nA	1

- (1) Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics except as listed in the Post Radiation Limits Table. These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate effect. Radiation end point limits for the noted parameters are specified only for the conditions as specified in MIL-STD-883, per Test Method 1019, Condition A.
- (2) Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics except as listed in the Post Radiation Limits Table. Low dose rate testing has been performed on a wafer-by-wafer basis, per Test Method 1019, Condition D of MIL-STD-883, with no enhanced low dose rate sensitivity (ELDRS).

## LM7171 ( $\pm 5$ ) Electrical Characteristics DC Parameters<sup>(1)(2)</sup>

The following conditions apply, unless otherwise specified.

DC:  $T_J = 25^\circ\text{C}$ ,  $V^+ = +5\text{V}$ ,  $V^- = -5\text{V}$ ,  $V_{CM} = 0\text{V}$ , and  $R_L > 1\text{M}\Omega$

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
$V_{IO}$	Input Offset Voltage			-1.5	1.5	mV	1
				-7.0	7.0	mV	2, 3
$+I_{IB}$	Input Bias Current				10	$\mu\text{A}$	1
					12	$\mu\text{A}$	2, 3
$-I_{IB}$	Input Bias Current				10	$\mu\text{A}$	1
					12	$\mu\text{A}$	2, 3
$I_{IO}$	Input Offset Current			-4.0	4.0	$\mu\text{A}$	1
				-6.0	6.0	$\mu\text{A}$	2, 3
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 2.5\text{V}$		80		dB	1
				70		dB	2, 3
$A_V$	Large Signal Voltage Gain	$R_L = 1\text{K}\Omega$ , $V_O = \pm 1\text{V}$	See <sup>(3)</sup>	75		dB	1
			See <sup>(3)</sup>	70		dB	2, 3
		$R_L = 100\Omega$ , $V_O = \pm 1\text{V}$	See <sup>(3)</sup>	72		dB	1
			See <sup>(3)</sup>	67		dB	2, 3
$V_O$	Output Swing	$R_L = 1\text{K}\Omega$		3.2	-3.2	V	1
				3.0	-3.0	V	2, 3
		$R_L = 100\Omega$		2.9	-2.9	V	1
				2.8	-2.75	V	2, 3
	Output Current (Open Loop)	Sourcing $R_L = 100\Omega$	See <sup>(4)</sup>	29		mA	1
			See <sup>(4)</sup>	28		mA	2, 3
		Sinking $R_L = 100\Omega$	See <sup>(4)</sup>		-29	mA	1
			See <sup>(4)</sup>		-27.5	mA	2, 3
$I_S$	Supply Current				8.0	mA	1
					9.0	mA	2, 3

- (1) Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics except as listed in the Post Radiation Limits Table. These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate effect. Radiation end point limits for the noted parameters are specified only for the conditions as specified in MIL-STD-883, per Test Method 1019, Condition A.
- (2) Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics except as listed in the Post Radiation Limits Table. Low dose rate testing has been performed on a wafer-by-wafer basis, per Test Method 1019, Condition D of MIL-STD-883, with no enhanced low dose rate sensitivity (ELDRS).
- (3) Large signal voltage gain is the total output swing divided by the input signal required to produce that swing. For  $V_S = \pm 15\text{V}$ ,  $V_{OUT} = \pm 5\text{V}$ . For  $V_S = \pm 5\text{V}$ ,  $V_{OUT} = \pm 1\text{V}$ .
- (4) The open loop output current is specified, by the measurement of the open loop output voltage swing, using  $100\Omega$  output load.

**LM7171 ( $\pm 5$ ) Electrical Characteristics DC Drift Parameters<sup>(1)(2)</sup>**

The following conditions apply, unless otherwise specified.

DC:  $T_J = 25^\circ\text{C}$ ,  $V^+ = +5\text{V}$ ,  $V^- = -5\text{V}$ ,  $V_{\text{CM}} = 0\text{V}$ , and  $R_L > 1\text{M}\Omega$

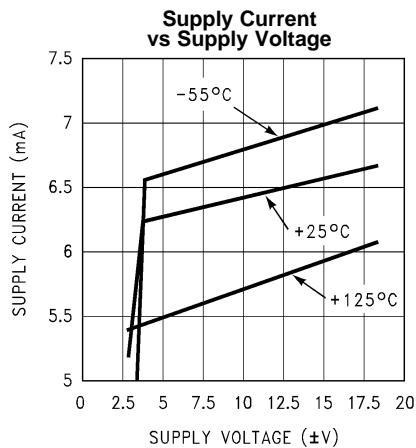
Delta calculations performed on QMLV devices at group B, subgroup 5.

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
$V_{\text{IO}}$	Input Offset Voltage			-250	250	$\mu\text{V}$	1
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$-I_{\text{Bias}}$	Input Bias Current			-500	500	nA	1

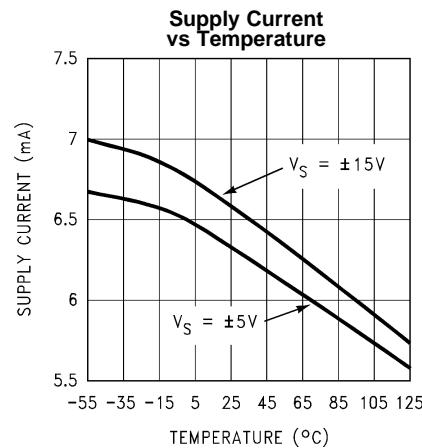
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- (2) Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics except as listed in the Post Radiation Limits Table. Low dose rate testing has been performed on a wafer-by-wafer basis, per Test Method 1019, Condition D of MIL-STD-883, with no enhanced low dose rate sensitivity (ELDRS).

### Typical Performance Characteristics

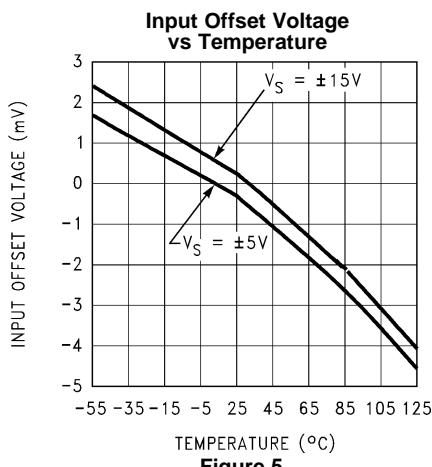
unless otherwise noted,  $T_A = 25^\circ\text{C}$



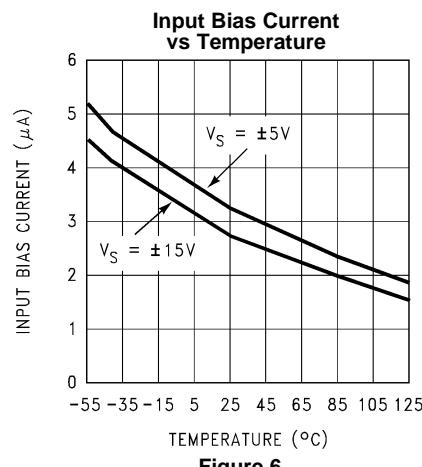
**Figure 3.**



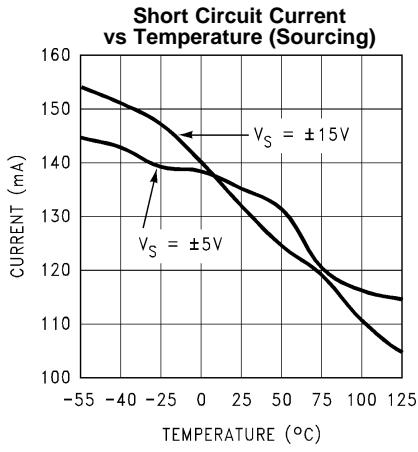
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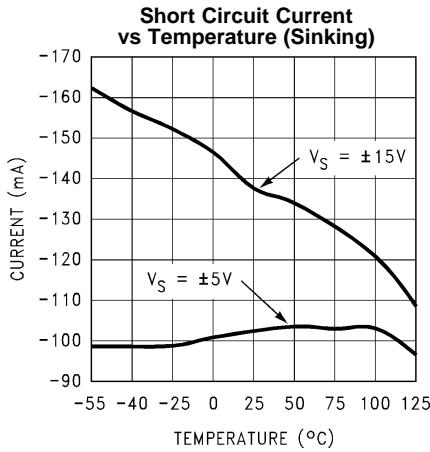
**Figure 5.**



**Figure 6.**



**Figure 7.**



**Figure 8.**

### Typical Performance Characteristics (continued)

unless otherwise noted,  $T_A = 25^\circ\text{C}$

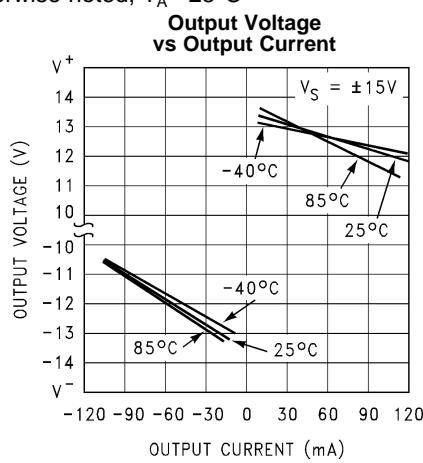


Figure 9.

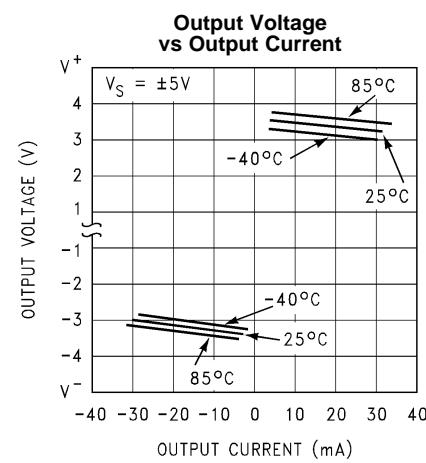


Figure 10.

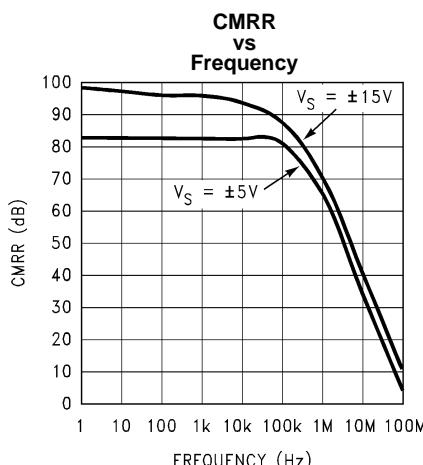


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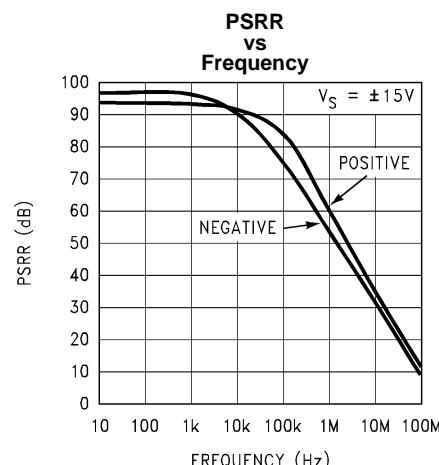


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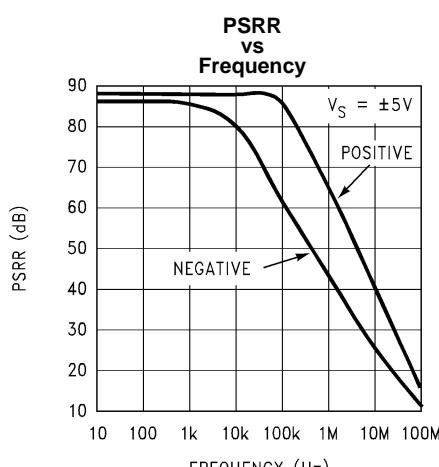


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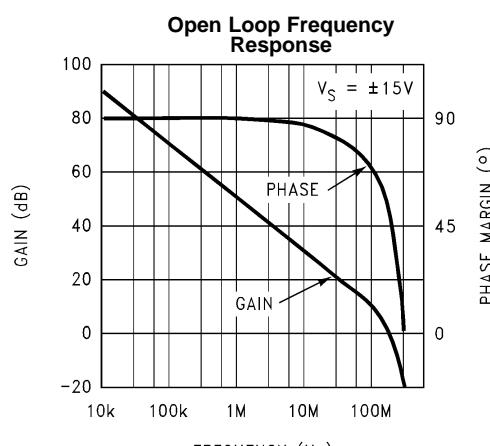
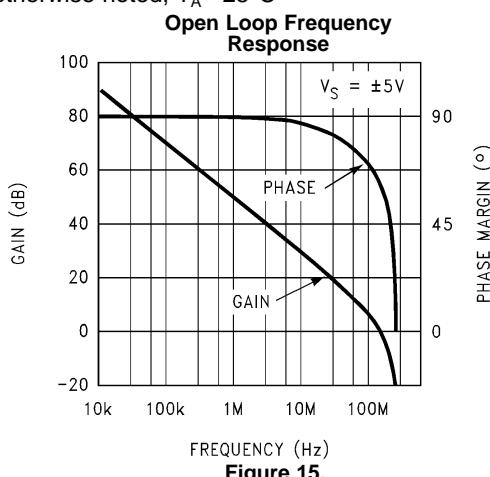


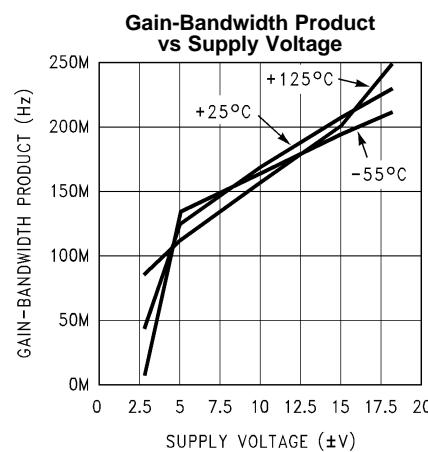
Figure 14.

### Typical Performance Characteristics (continued)

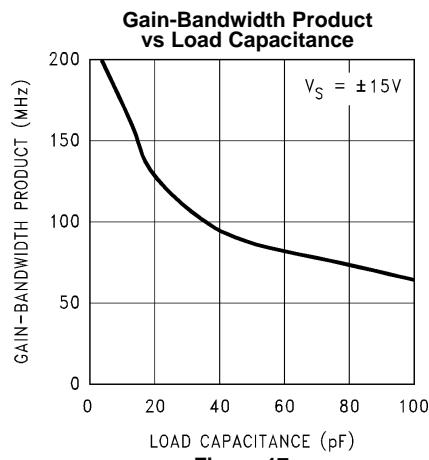
unless otherwise noted,  $T_A = 25^\circ\text{C}$



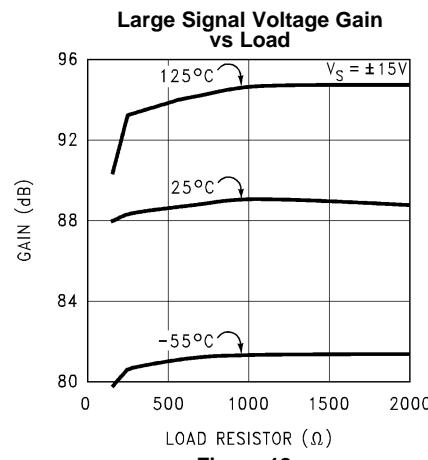
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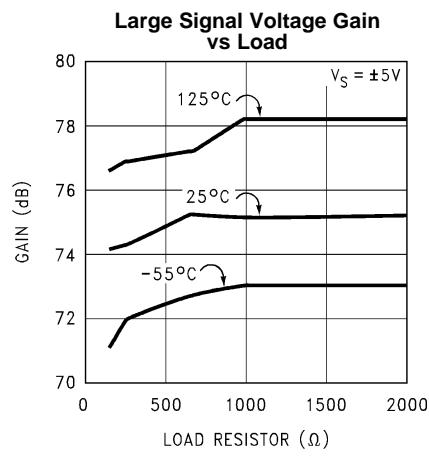
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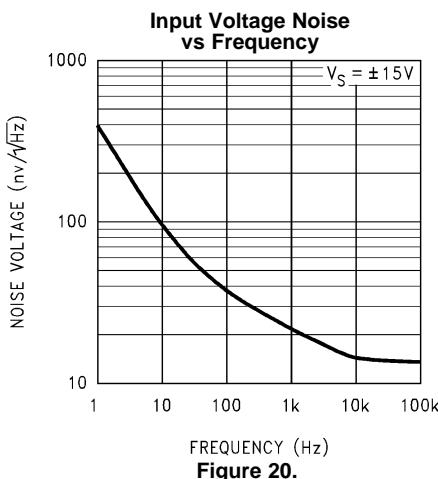
**Figure 17.**



**Figure 18.**



**Figure 19.**



**Figure 20.**

### Typical Performance Characteristics (continued)

unless otherwise noted,  $T_A = 25^\circ\text{C}$

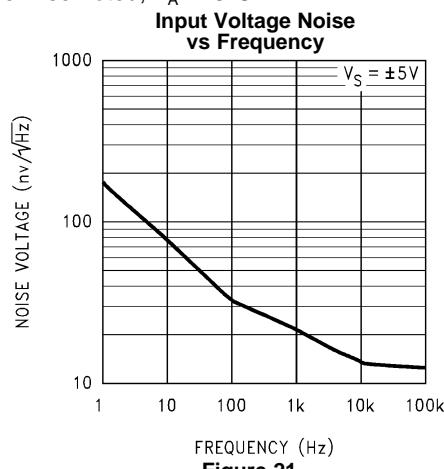


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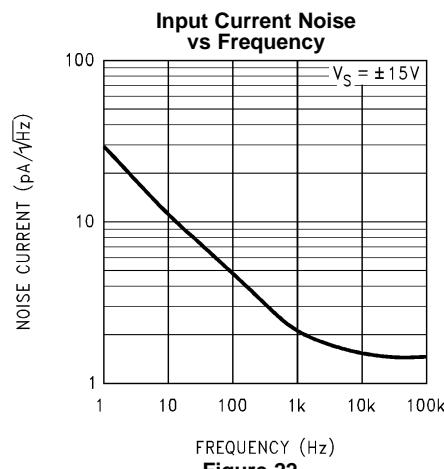


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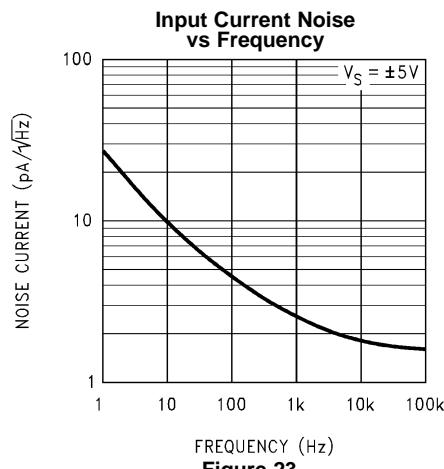


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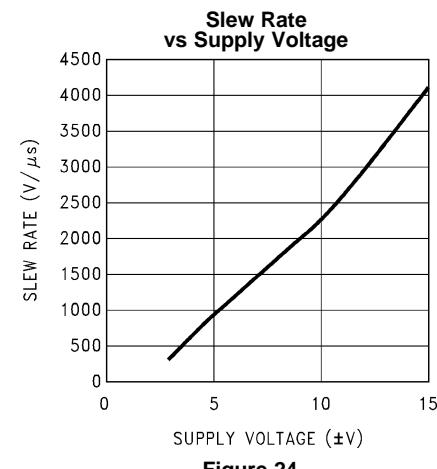


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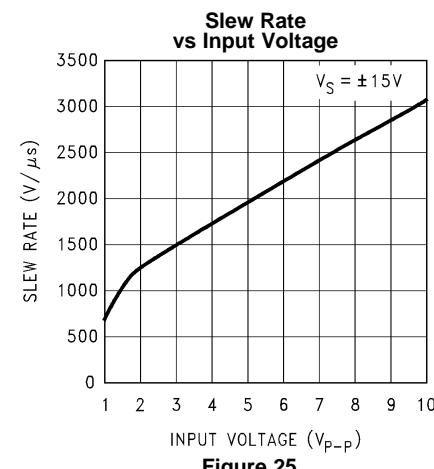


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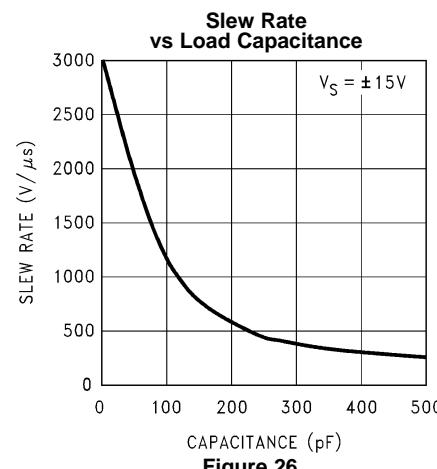
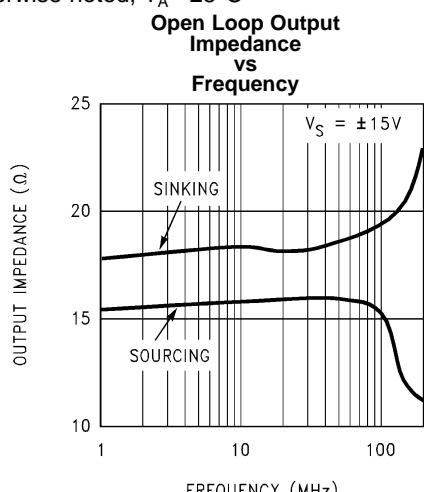


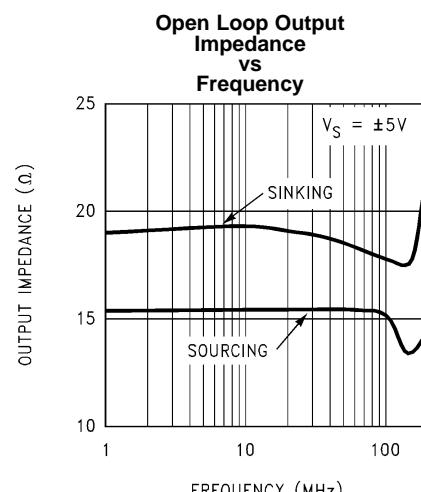
Figure 26.

### Typical Performance Characteristics (continued)

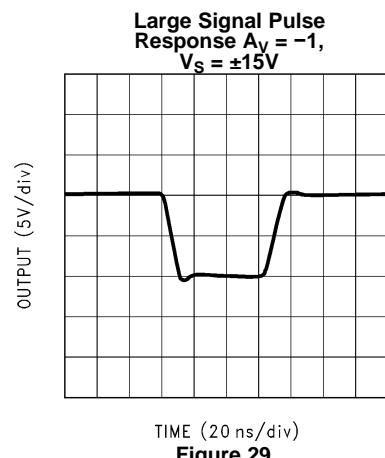
unless otherwise noted,  $T_A = 25^\circ\text{C}$



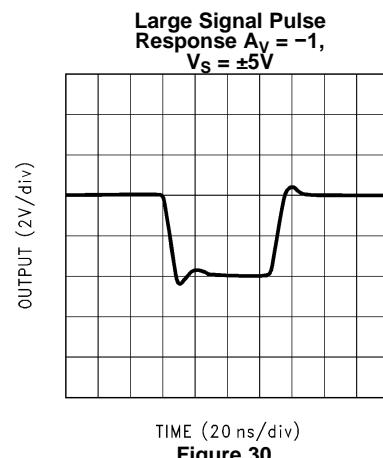
**Figure 27.**



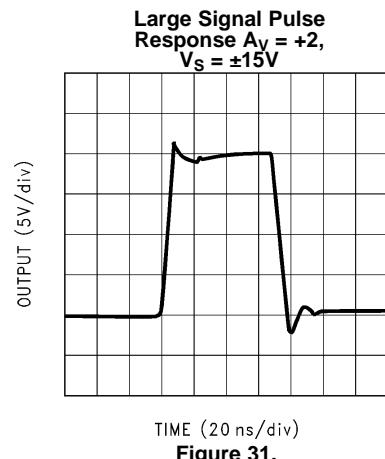
**Figure 28.**



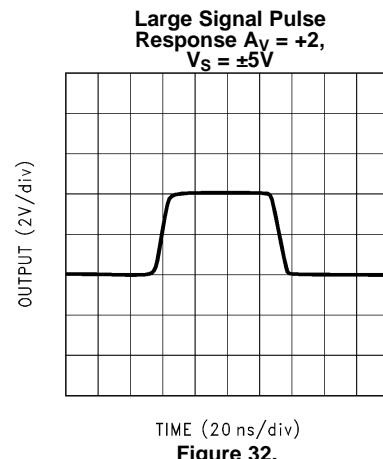
**Figure 29.**



**Figure 30.**



**Figure 31.**



**Figure 32.**

### Typical Performance Characteristics (continued)

unless otherwise noted,  $T_A = 25^\circ\text{C}$

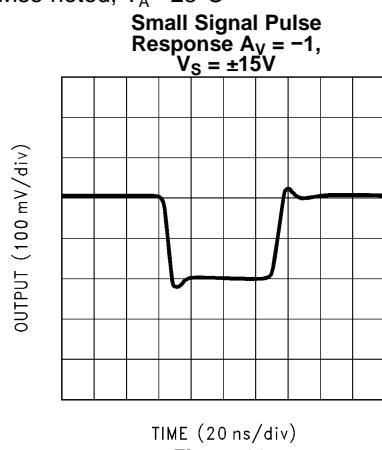


Figure 33.

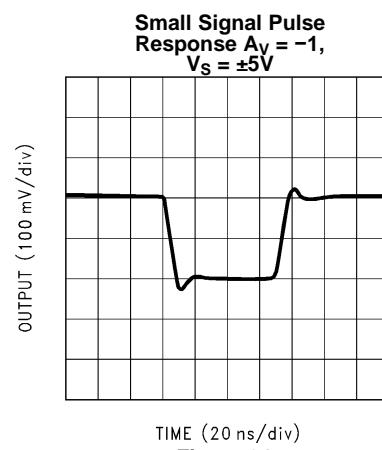


Figure 34.

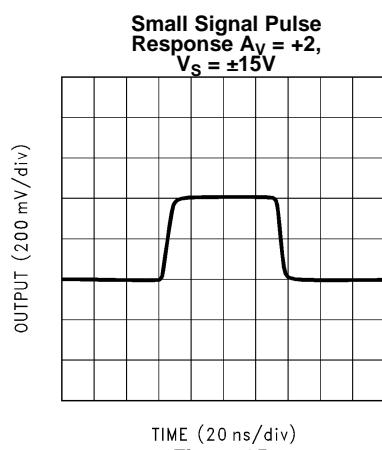


Figure 35.

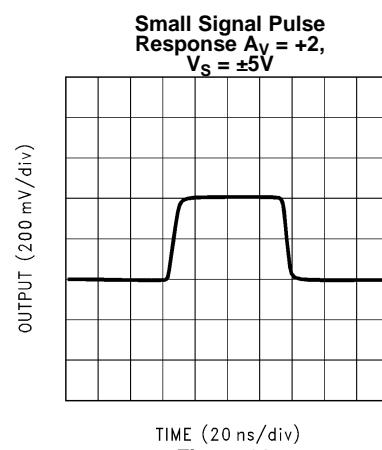


Figure 36.

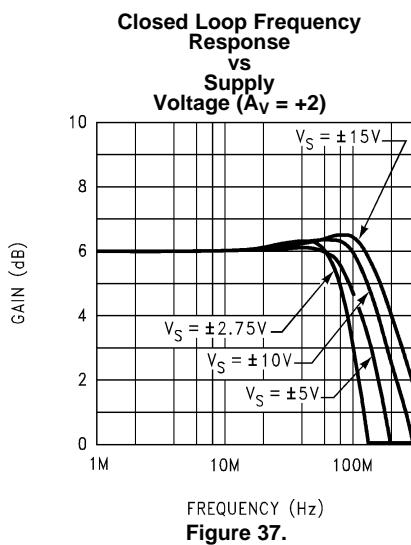


Figure 37.

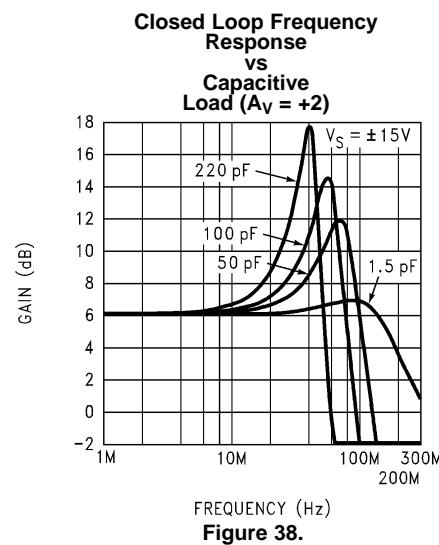


Figure 38.

### Typical Performance Characteristics (continued)

unless otherwise noted,  $T_A = 25^\circ\text{C}$

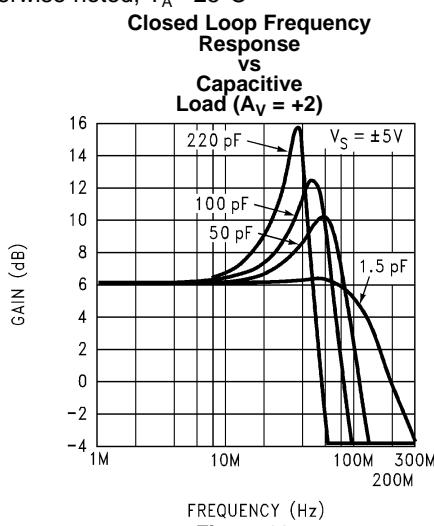


Figure 39.

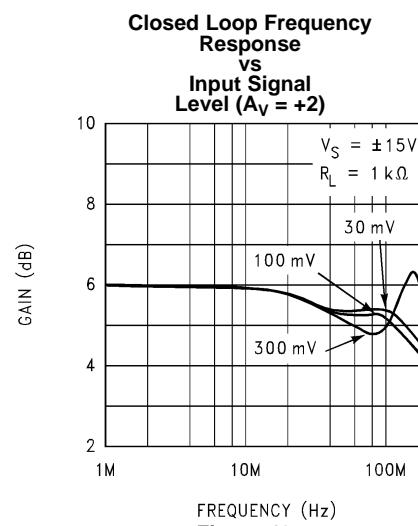


Figure 40.

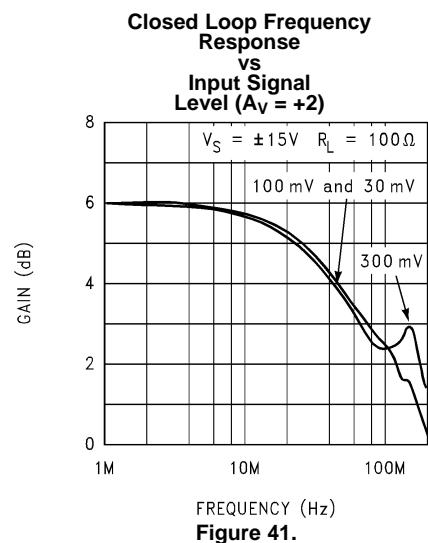


Figure 41.

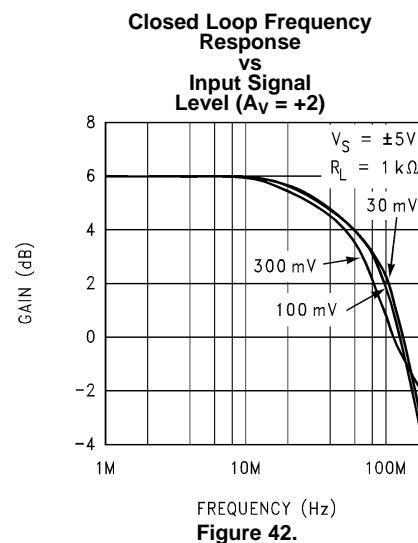


Figure 42.

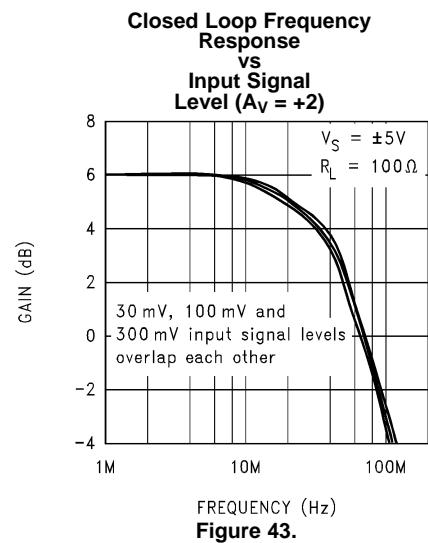


Figure 43.

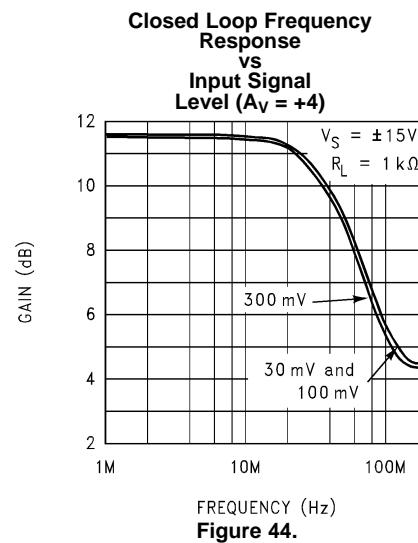


Figure 44.

### Typical Performance Characteristics (continued)

unless otherwise noted,  $T_A = 25^\circ\text{C}$

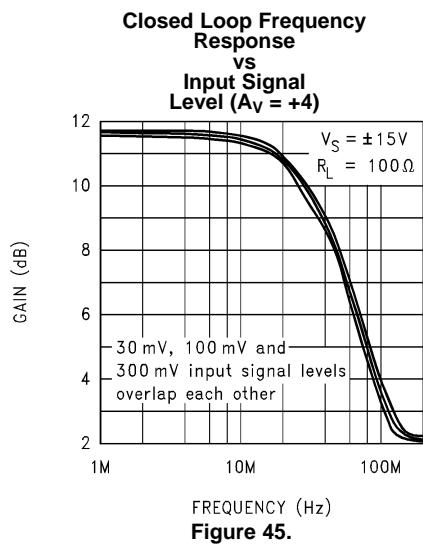


Figure 45.

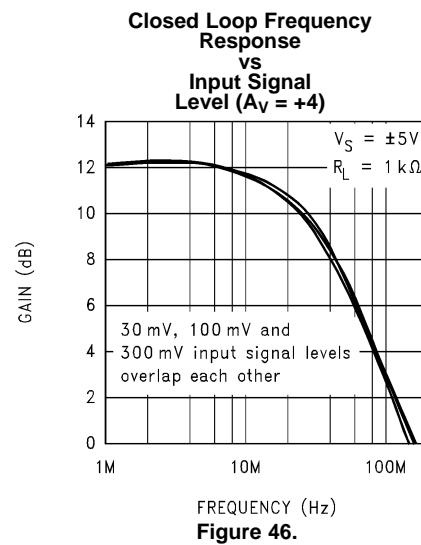


Figure 46.

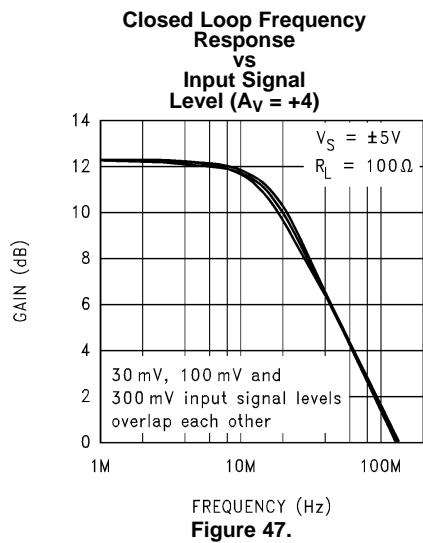


Figure 47.

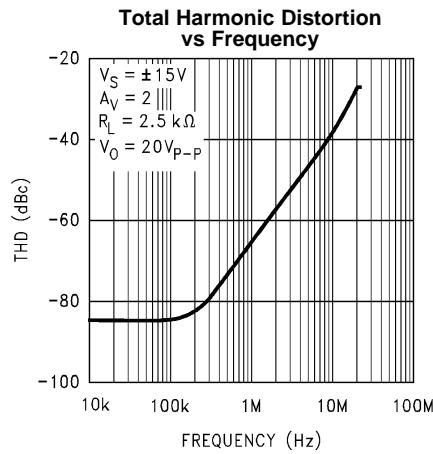


Figure 48.

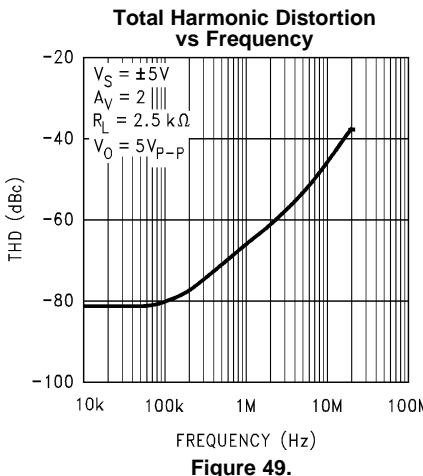


Figure 49.

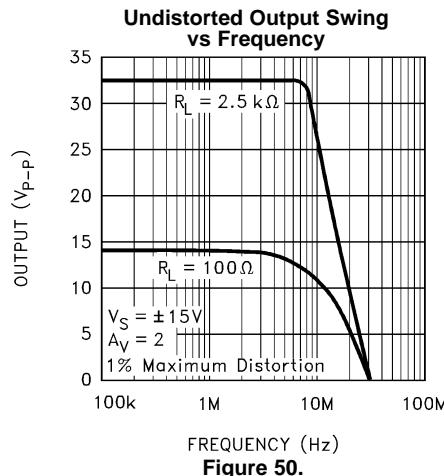
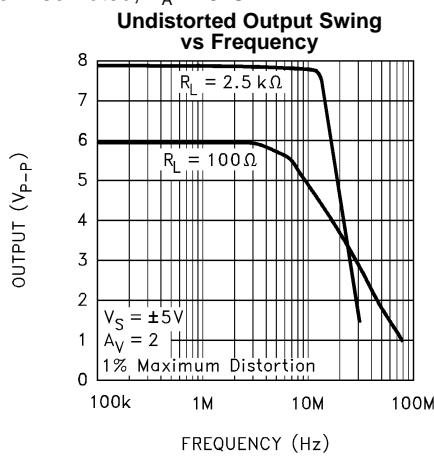


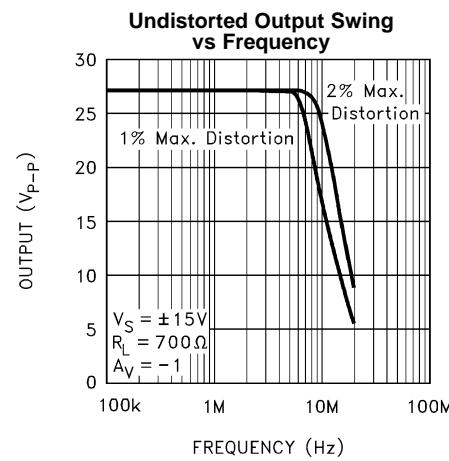
Figure 50.

### Typical Performance Characteristics (continued)

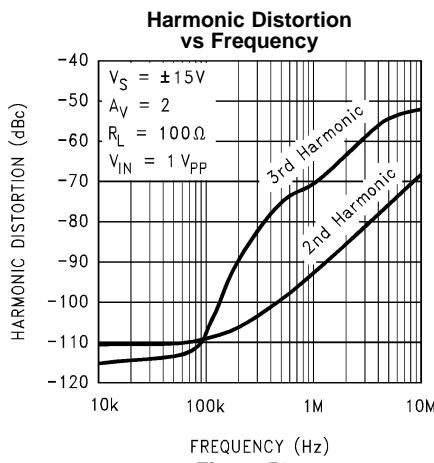
unless otherwise noted,  $T_A = 25^\circ\text{C}$



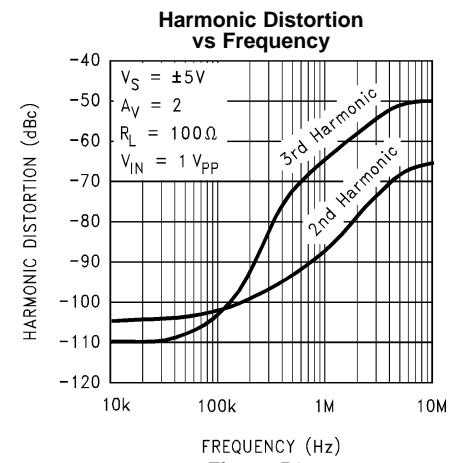
**Figure 51.**



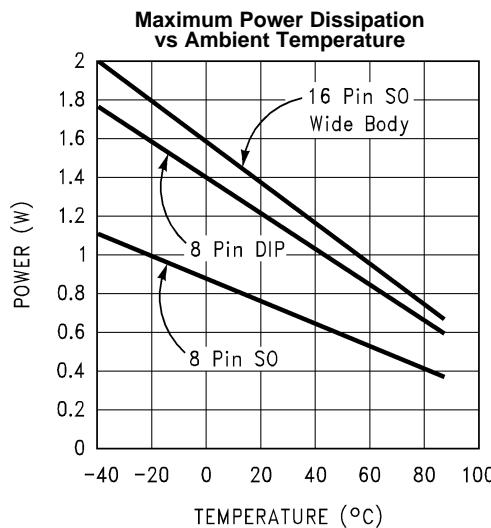
**Figure 52.**



**Figure 53.**



**Figure 54.**



The THD measurement at low frequency is limited by the test instrument.

**Figure 55.**

## APPLICATION NOTES

### LM7171 Performance Discussion

The LM7171 is a very high speed, voltage feedback amplifier. It consumes only 6.5 mA supply current while providing a unity-gain bandwidth of 200 MHz and a slew rate of 4100V/μs. It also has other great features such as low differential gain and phase and high output current.

The LM7171 is a true voltage feedback amplifier. Unlike current feedback amplifiers (CFAs) with a low inverting input impedance and a high non-inverting input impedance, both inputs of voltage feedback amplifiers (VFAs) have high impedance nodes. The low impedance inverting input in CFAs and a feedback capacitor create an additional pole that will lead to instability. As a result, CFAs cannot be used in traditional op amp circuits such as photodiode amplifiers, I-to-V converters and integrators where a feedback capacitor is required.

### LM7171 Circuit Operation

The class AB input stage in the LM7171 is fully symmetrical and has a similar slewing characteristic to the current feedback amplifiers. In the LM7171 Simplified Schematic, Q1 through Q4 form the equivalent of the current feedback input buffer,  $R_E$  the equivalent of the feedback resistor, and stage A buffers the inverting input. The triple-buffered output stage isolates the gain stage from the load to provide low output impedance.

### LM7171 Slew Rate Characteristic

The slew rate of the LM7171 is determined by the current available to charge and discharge an internal high impedance node capacitor. This current is the differential input voltage divided by the total degeneration resistor  $R_E$ . Therefore, the slew rate is proportional to the input voltage level, and the higher slew rates are achievable in the lower gain configurations. A curve of slew rate versus input voltage level is provided in the “Typical Performance Characteristics”.

When a very fast large signal pulse is applied to the input of an amplifier, some overshoot or undershoot occurs. By placing an external resistor such as 1 kΩ in series with the input of the LM7171, the bandwidth is reduced to help lower the overshoot.

### Slew Rate Limitation

If the amplifier's input signal has too large of an amplitude at too high of a frequency, the amplifier is said to be slew rate limited; this can cause ringing in time domain and peaking in frequency domain at the output of the amplifier.

In the [Typical Performance Characteristics](#) section, there are several curves of  $A_V = +2$  and  $A_V = +4$  versus input signal levels. For the  $A_V = +4$  curves, no peaking is present and the LM7171 responds identically to the different input signal levels of 30 mV, 100 mV and 300 mV.

For the  $A_V = +2$  curves, slight peaking occurs. This peaking at high frequency (>100 MHz) is caused by a large input signal at high enough frequency that exceeds the amplifier's slew rate. The peaking in frequency response does not limit the pulse response in time domain, and the LM7171 is stable with noise gain of  $\geq +2$ .

### Layout Consideration

#### PRINTED CIRCUIT BOARDS AND HIGH SPEED OP AMPS

There are many things to consider when designing PC boards for high speed op amps. Without proper caution, it is very easy to have excessive ringing, oscillation and other degraded AC performance in high speed circuits. As a rule, the signal traces should be short and wide to provide low inductance and low impedance paths. Any unused board space needs to be grounded to reduce stray signal pickup. Critical components should also be grounded at a common point to eliminate voltage drop. Sockets add capacitance to the board and can affect high frequency performance. It is better to solder the amplifier directly into the PC board without using any socket.

### USING PROBES

Active (FET) probes are ideal for taking high frequency measurements because they have wide bandwidth, high input impedance and low input capacitance. However, the probe ground leads provide a long ground loop that will produce errors in measurement. Instead, the probes can be grounded directly by removing the ground leads and probe jackets and using scope probe jacks.

## COMPONENT SELECTION AND FEEDBACK RESISTOR

It is important in high speed applications to keep all component leads short. For discrete components, choose carbon composition-type resistors and mica-type capacitors. Surface mount components are preferred over discrete components for minimum inductive effect.

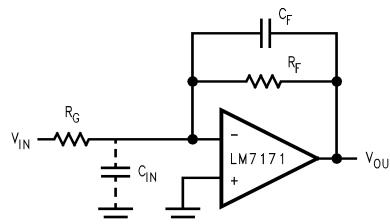
Large values of feedback resistors can couple with parasitic capacitance and cause undesirable effects such as ringing or oscillation in high speed amplifiers. For the LM7171, a feedback resistor of  $510\Omega$  gives optimal performance.

## Compensation for Input Capacitance

The combination of an amplifier's input capacitance with the gain setting resistors, adds a pole that can cause peaking or oscillation. To solve this problem, a feedback capacitor with a value

$$C_F > (R_G \times C_{IN})/R_F \quad (1)$$

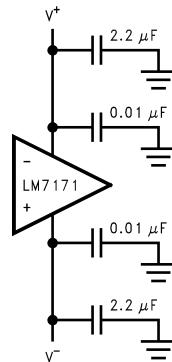
can be used to cancel that pole. For the LM7171, a feedback capacitor of 2 pF is recommended. [Figure 56](#) illustrates the compensation circuit.



**Figure 56. Compensating for Input Capacitance**

## Power Supply Bypassing

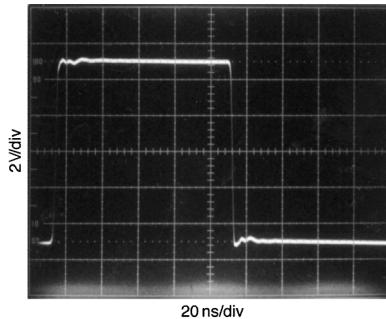
Bypassing the power supply is necessary to maintain low power supply impedance across frequency. Both positive and negative power supplies should be bypassed individually by placing 0.01  $\mu$ F ceramic capacitors directly to power supply pins and 2.2  $\mu$ F tantalum capacitors close to the power supply pins.



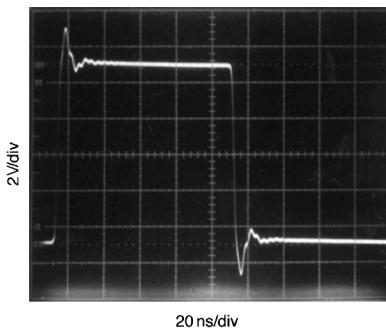
**Figure 57. Power Supply Bypassing**

## Termination

In high frequency applications, reflections occur if signals are not properly terminated. [Figure 58](#) shows a properly terminated signal while [Figure 59](#) shows an improperly terminated signal.



**Figure 58. Properly Terminated Signal**

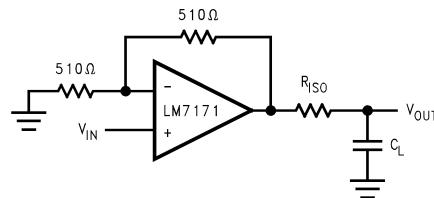


**Figure 59. Improperly Terminated Signal**

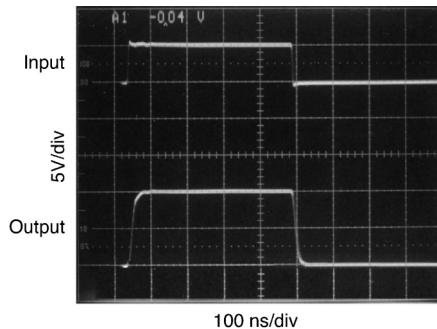
To minimize reflection, coaxial cable with matching characteristic impedance to the signal source should be used. The other end of the cable should be terminated with the same value terminator or resistor. For the commonly used cables, RG59 has  $75\Omega$  characteristic impedance, and RG58 has  $50\Omega$  characteristic impedance.

### Driving Capacitive Loads

Amplifiers driving capacitive loads can oscillate or have ringing at the output. To eliminate oscillation or reduce ringing, an isolation resistor can be placed as shown below in [Figure 60](#). The combination of the isolation resistor and the load capacitor forms a pole to increase stability by adding more phase margin to the overall system. The desired performance depends on the value of the isolation resistor; the bigger the isolation resistor, the more damped the pulse response becomes. For LM7171, a  $50\Omega$  isolation resistor is recommended for initial evaluation. [Figure 61](#) shows the LM7171 driving a  $150\text{ pF}$  load with the  $50\Omega$  isolation resistor.



**Figure 60. Isolation Resistor Used to Drive Capacitive Load**



**Figure 61. The LM7171 Driving a 150 pF Load with a 50Ω Isolation Resistor**

## Power Dissipation

The maximum power allowed to dissipate in a device is defined as:

$$P_D = (T_{J(\max)} - T_A)/\theta_{JA} \quad (2)$$

### Where

$P_D$  is the power dissipation in a device

$T_{J(\max)}$  is the maximum junction temperature

$T_A$  is the ambient temperature

$\theta_{JA}$  is the thermal resistance of a particular package

For example, for the LM7171 in a CFP package, the maximum power dissipation at 25°C ambient temperature is 680 mW.

Thermal resistance,  $\theta_{JA}$ , depends on parameters such as die size, package size and package material. The smaller the die size and package, the higher  $\theta_{JA}$  becomes. The 8-pin CDIP package has a lower thermal resistance (106°C/W) than that of the CFP (182°C/W). Therefore, for higher dissipation capability, use an 8-pin CDIP package.

The total power dissipated in a device can be calculated as:

$$P_D = P_Q + P_L \quad (3)$$

$P_Q$  is the quiescent power dissipated in a device with no load connected at the output.  $P_L$  is the power dissipated in the device with a load connected at the output; it is not the power dissipated by the load.

Furthermore,

$P_Q$ : = supply current  $\times$  total supply voltage with no load

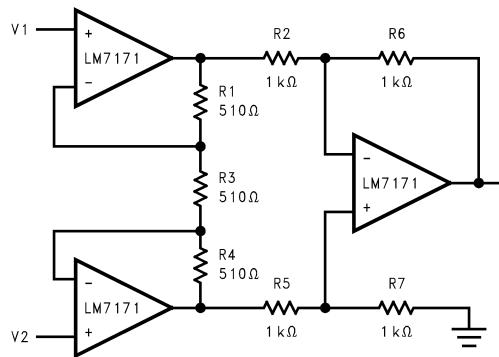
$P_L$ : = output current  $\times$  (voltage difference between supply voltage and output voltage of the same side of supply voltage)

For example, the total power dissipated by the LM7171 with  $V_S = \pm 15V$  and output voltage of 10V into 1 kΩ is

$$\begin{aligned} P_D &= P_Q + P_L \\ &= (6.5 \text{ mA}) \times (30V) + (10 \text{ mA}) \times (15V - 10V) \\ &= 195 \text{ mW} + 50 \text{ mW} \\ &= 245 \text{ mW} \end{aligned}$$

## Application Circuit

**Figure 62. Fast Instrumentation Amplifier**

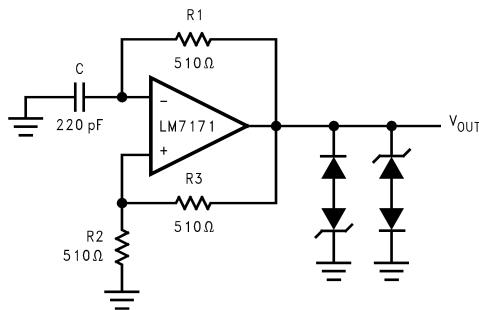


$$V_{IN} = V_2 - V_1$$

if  $R6 = R2$ ,  $R7 = R5$ , and  $R1 = R4$

$$\frac{V_{OUT}}{V_{IN}} = \frac{R6}{R2} \left( 1 + 2 \frac{R1}{R3} \right) = 3$$

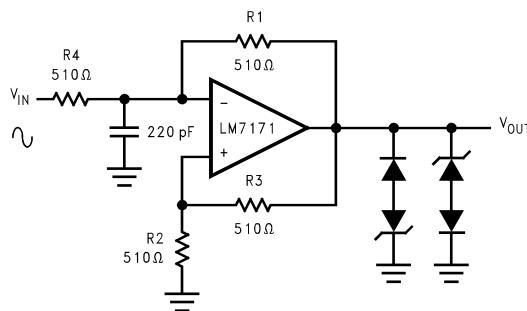
**Figure 63. Multivibrator**

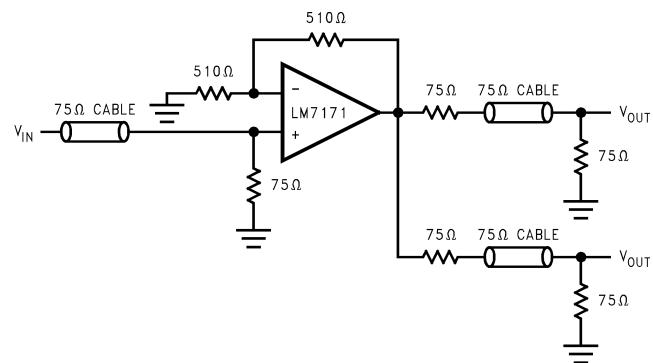


$$f = \frac{1}{2 \left( R1 C \ln \left( 1 + 2 \frac{R2}{R3} \right) \right)}$$

$f = 4 \text{ MHz}$

**Figure 64. Pulse Width Modulator**



**Figure 65. Video Line Driver**

## REVISION HISTORY

Released	Revision	Section	Changes
02/04/09	A	New Release, Corporate format	1 MDS data sheet converted into one Corp. data sheet format. Added ELDRS NSID's to Ordering Information Table. MNLM7171AM-X-RH Rev 0C0 will be archived.

### Changes from Revision B (April 2013) to Revision C

### Page

- Changed layout of National Data Sheet to TI format ..... [23](#)

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-9553601QPA	Active	Production	CDIP (NAB)   8	40   TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AMJQML 5962-95536 01QPA Q ACO 01QPA Q >T
5962-9553601QXA	Active	Production	CFP (NAC)   10	54   JEDEC TRAY (5+1)	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AM WG Q 5962-95536 01QXA ACO 01QXA >T
5962F9553601VHA	Active	Production	CFP (NAD)   10	19   TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AM WFQMLV Q 5962F95536 01VHA ACO 01VHA >T
5962F9553601VPA	Active	Production	CDIP (NAB)   8	40   TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AMJFQV 5962F95536 01VPA Q ACO 01VPA Q >T
5962F9553601VXA	Active	Production	CFP (NAC)   10	54   JEDEC TRAY (5+1)	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AM WGFQMLV Q 5962F95536 01VXA ACO 01VXA >T
LM7171AMJ-QML	Active	Production	CDIP (NAB)   8	40   TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AMJQML 5962-95536 01QPA Q ACO 01QPA Q >T
LM7171AMJ-QML.A	Active	Production	CDIP (NAB)   8	40   TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AMJQML 5962-95536 01QPA Q ACO 01QPA Q >T
LM7171AMJFQMLV	Active	Production	CDIP (NAB)   8	40   TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AMJFQV 5962F95536 01VPA Q ACO 01VPA Q >T

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM7171AMJFQMLV.A	Active	Production	CDIP (NAB)   8	40   TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AMJFQV 5962F95536 01VPA Q ACO 01VPA Q >T
LM7171AMWFQMLV	Active	Production	CFP (NAD)   10	19   TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AM WFQMLV Q 5962F95536 01VHA ACO 01VHA >T
LM7171AMWFQMLV.A	Active	Production	CFP (NAD)   10	19   TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AM WFQMLV Q 5962F95536 01VHA ACO 01VHA >T
LM7171AMWG-QML	Active	Production	CFP (NAC)   10	54   JEDEC TRAY (5+1)	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AM WG Q 5962-95536 01QXA ACO 01QXA >T
LM7171AMWG-QML.A	Active	Production	CFP (NAC)   10	54   JEDEC TRAY (5+1)	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AM WG Q 5962-95536 01QXA ACO 01QXA >T
LM7171AMWGFQMLV	Active	Production	CFP (NAC)   10	54   JEDEC TRAY (5+1)	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AM WGFQMLV Q 5962F95536 01VXA ACO 01VXA >T
LM7171AMWGFQMLV.A	Active	Production	CFP (NAC)   10	54   JEDEC TRAY (5+1)	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171AM WGFQMLV Q 5962F95536 01VXA ACO 01VXA >T
LM7171NAB/EM	Active	Production	CDIP (NAB)   8	40   TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM7171NABEM

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

**(2) Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

**(3) RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

**(4) Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**(5) MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

**(6) Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

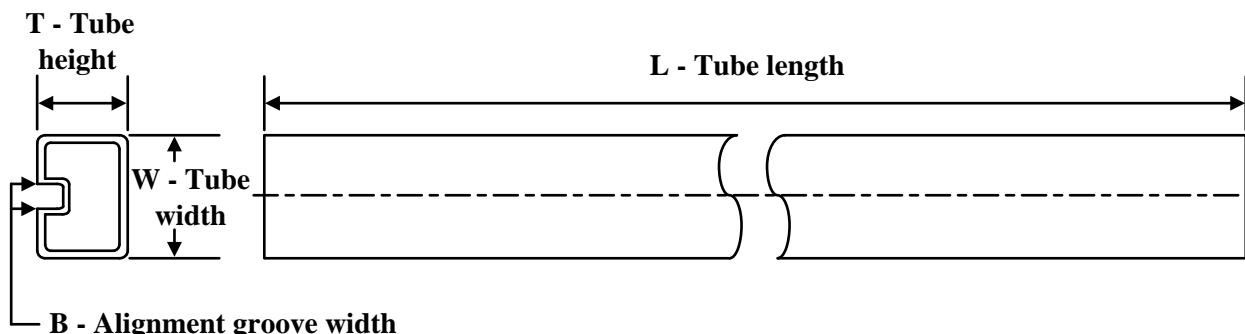
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF LM7171QML, LM7171QML-SP :**

- Military : [LM7171QML](#)
- Space : [LM7171QML-SP](#)

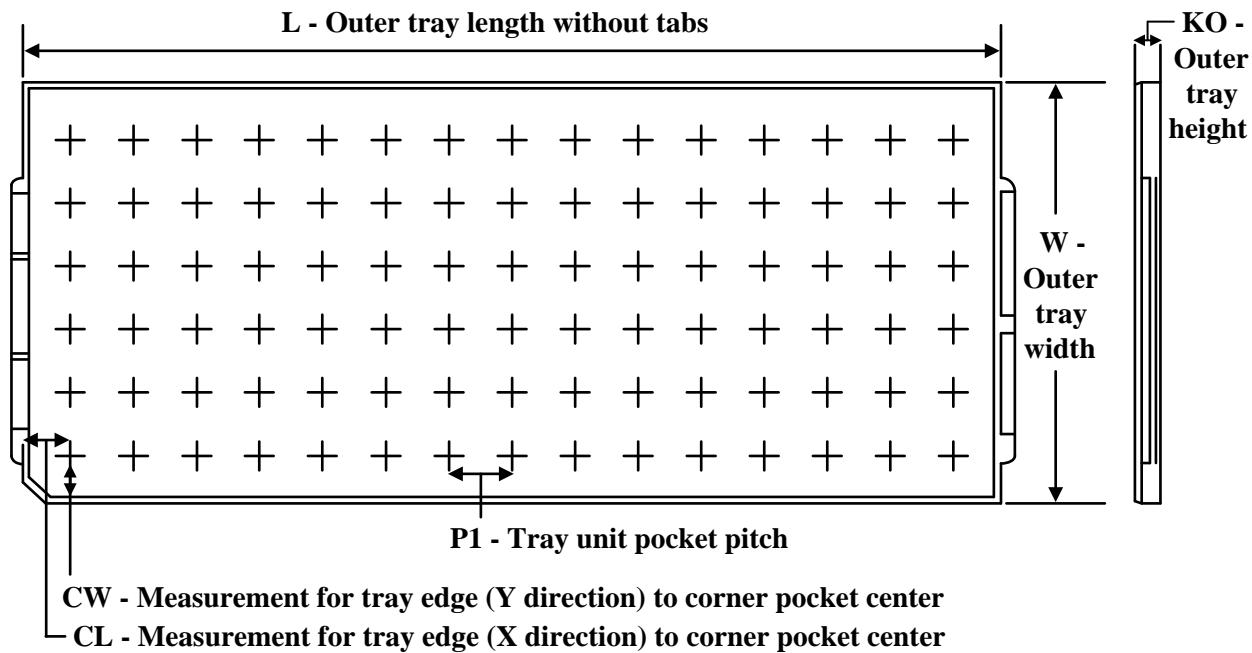
NOTE: Qualified Version Definitions:

- Military - QML certified for Military and Defense Applications
- Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application

**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
5962-9553601QPA	NAB	CDIP	8	40	506.98	15.24	13440	NA
5962F9553601VHA	NAD	CFP	10	19	502	23	9398	9.78
5962F9553601VPA	NAB	CDIP	8	40	506.98	15.24	13440	NA
LM7171AMJ-QML	NAB	CDIP	8	40	506.98	15.24	13440	NA
LM7171AMJ-QML.A	NAB	CDIP	8	40	506.98	15.24	13440	NA
LM7171AMJFQMLV	NAB	CDIP	8	40	506.98	15.24	13440	NA
LM7171AMJFQMLV.A	NAB	CDIP	8	40	506.98	15.24	13440	NA
LM7171AMWFQMLV	NAD	CFP	10	19	502	23	9398	9.78
LM7171AMWFQMLV.A	NAD	CFP	10	19	502	23	9398	9.78
LM7171NAB/EM	NAB	CDIP	8	40	506.98	15.24	13440	NA

**TRAY**


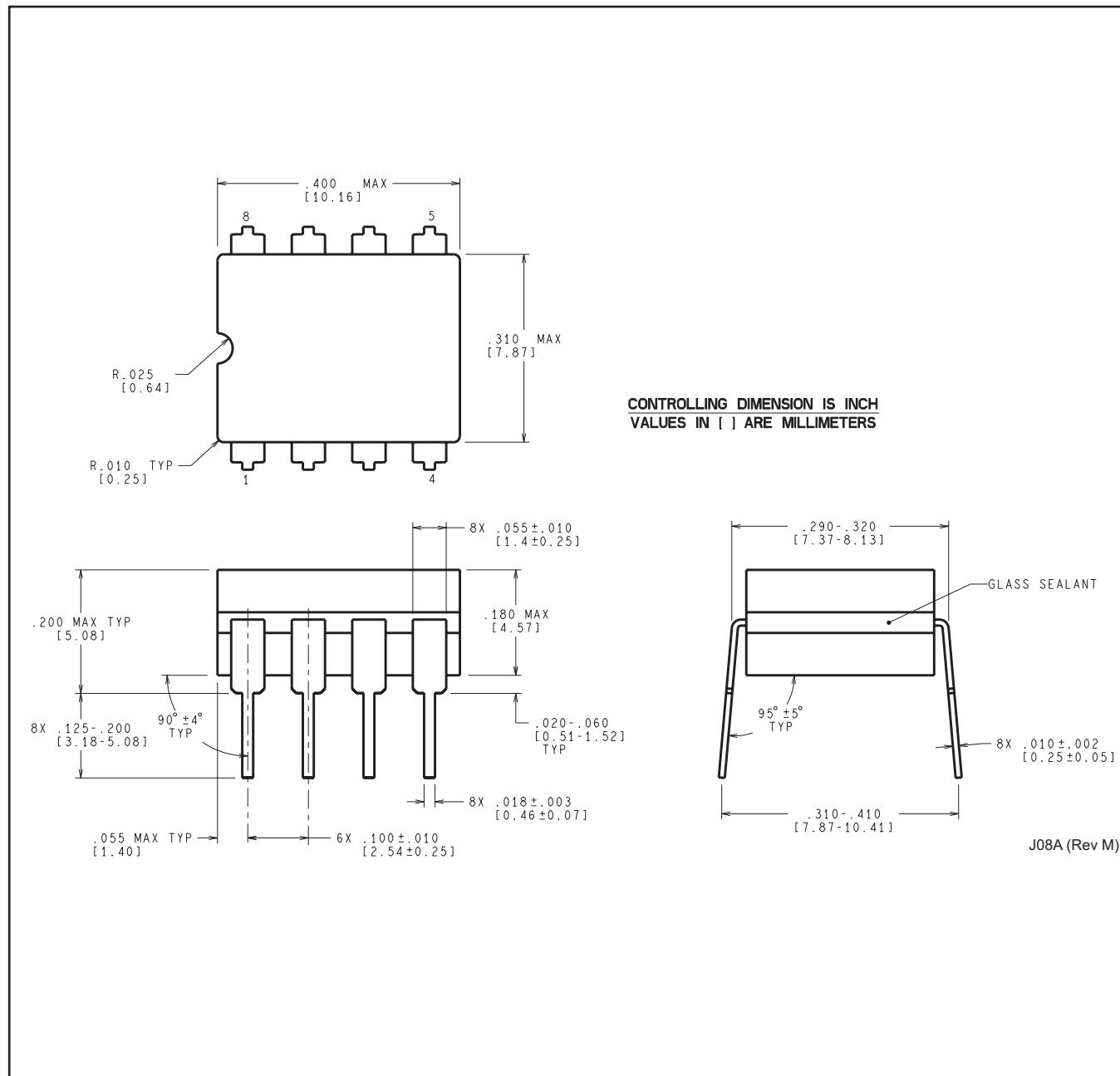
Chamfer on Tray corner indicates Pin 1 orientation of packed units.

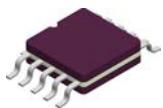
\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	Unit array matrix	Max temperature (°C)	L (mm)	W (mm)	K0 (µm)	P1 (mm)	CL (mm)	CW (mm)
5962-9553601QXA	NAC	CFP	10	54	6 X 9	100	101.6	101.6	8001	2.78	16.08	16.08
5962F9553601VXA	NAC	CFP	10	54	6 X 9	100	101.6	101.6	8001	2.78	16.08	16.08
LM7171AMWG-QML	NAC	CFP	10	54	6 X 9	100	101.6	101.6	8001	2.78	16.08	16.08
LM7171AMWG-QML.A	NAC	CFP	10	54	6 X 9	100	101.6	101.6	8001	2.78	16.08	16.08
LM7171AMWGFQMLV	NAC	CFP	10	54	6 X 9	100	101.6	101.6	8001	2.78	16.08	16.08
LM7171AMWGFQMLV.A	NAC	CFP	10	54	6 X 9	100	101.6	101.6	8001	2.78	16.08	16.08

## MECHANICAL DATA

### NAB0008A



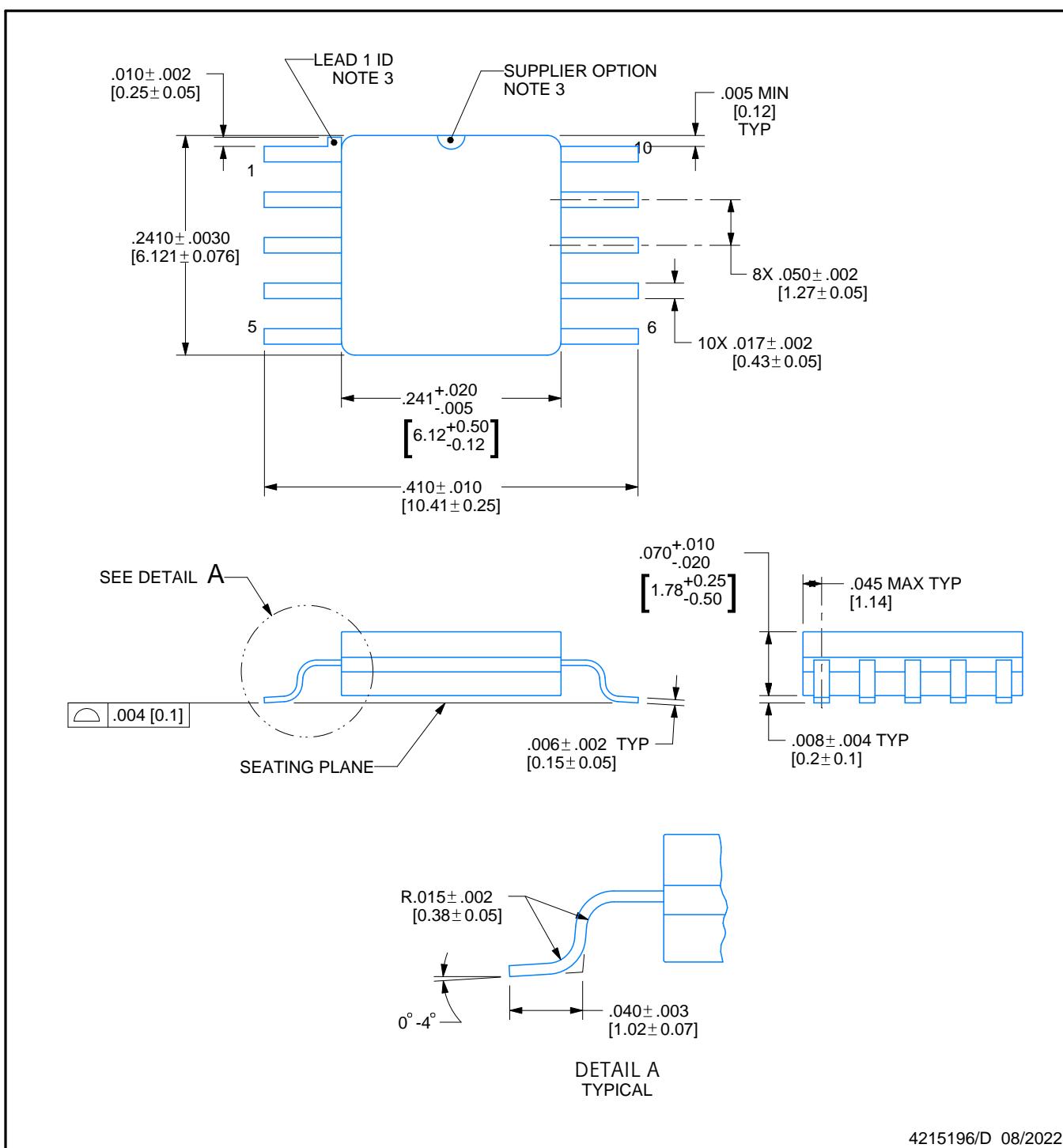


# PACKAGE OUTLINE

**NAC0010A**

**CFP - 2.33mm max height**

CERAMIC FLATPACK



NOTES:

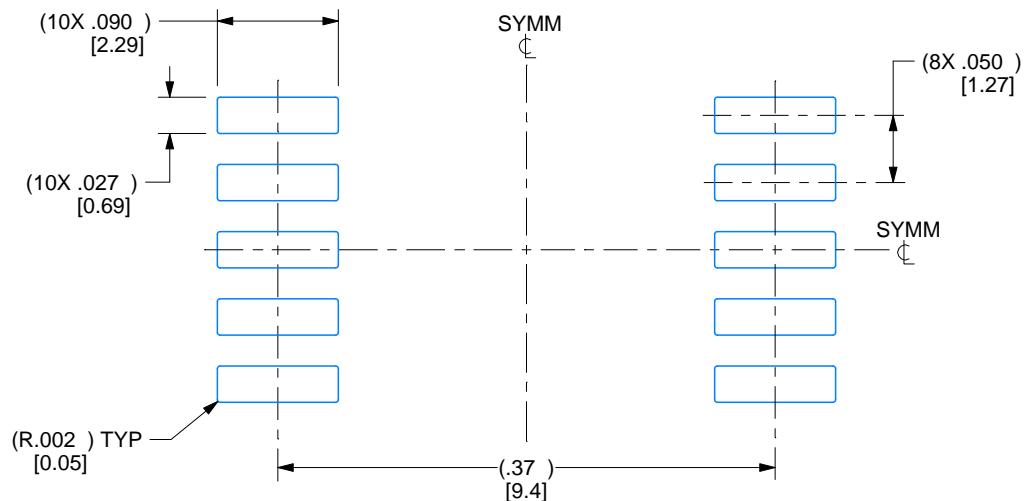
1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. For solder thickness and composition, see the "Lead Finish Composition/Thickness" link in the packaging section of the Texas Instruments website
3. Lead 1 identification shall be:
  - a) A notch or other mark within this area
  - b) A tab on lead 1, either side
4. No JEDEC registration as of December 2021

# EXAMPLE BOARD LAYOUT

NAC0010A

CFP - 2.33mm max height

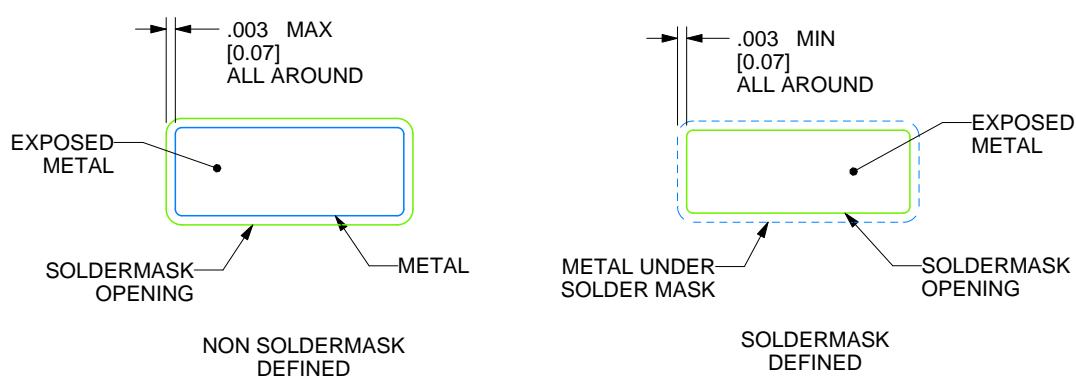
CERAMIC FLATPACK



## LAND PATTERN EXAMPLE

EXPOSED METAL SHOWN

SCALE: 7X



4215196/D 08/2022

## REVISIONS

REV	DESCRIPTION	E.C.N.	DATE	BY/APP'D
A	RELEASE TO DOCUMENT CONTROL	2197877	12/30/2021	DAVID CHIN / ANIS FAUZI
B	NO CHANGE TO DRAWING; REVISION FOR YODA RELEASE;	2198820	02/14/2022	K. SINCERBOX
C	CHANGE PIN 1 ID LOCATION ON PIN	2198845	02/18/2022	D. CHIN / K. SINCERBOX
D	.2410±.0030 WAS .2700 +.0012/- .0002;	2200915	08/08/2022	D. CHIN / K. SINCERBOX

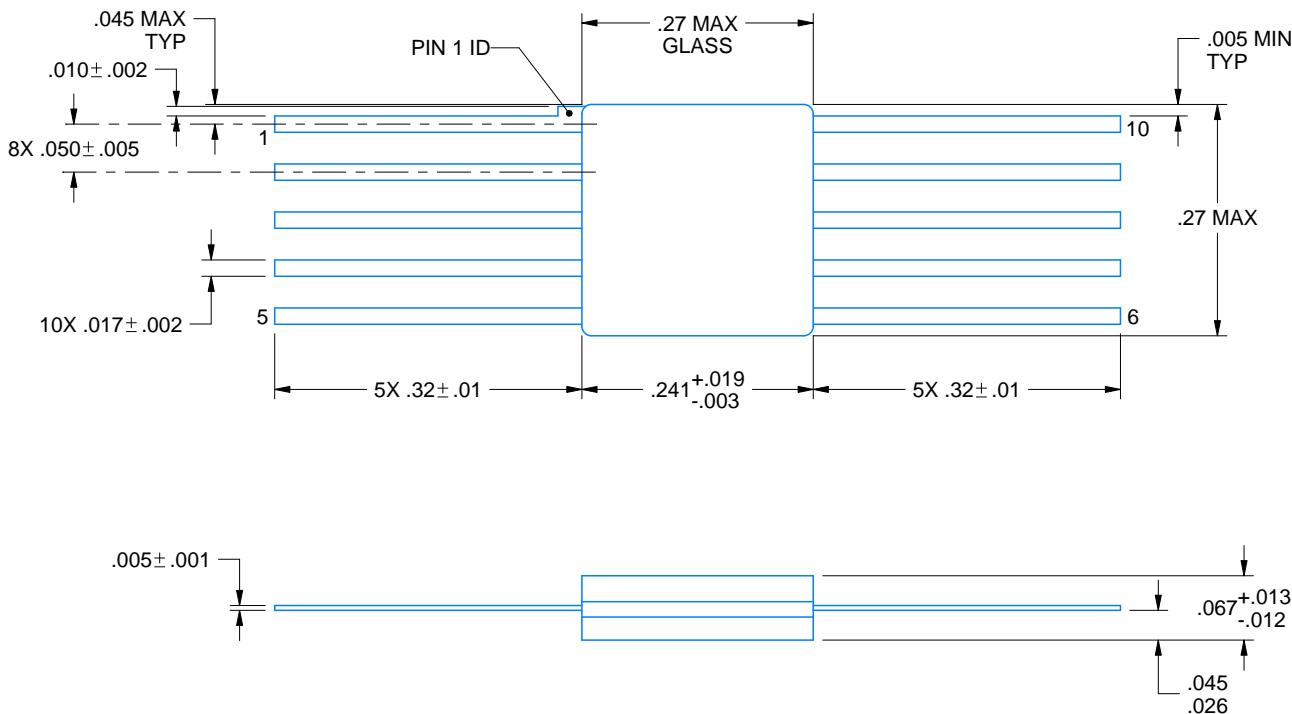
NAD0010A



# PACKAGE OUTLINE

CFP - 2.03 mm max height

CERAMIC FLATPACK



4215191/A 06/2021

NOTES:

1. All linear dimensions are in inches. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

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